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December 2012

FDMS2572 N-Channel UltraFET Trench[®] MOSFET

FDMS2572 N-Channel UltraFET Trench[®] MOSFET 150V, 27A, 47mΩ

Features

- Max $r_{DS(on)}$ = 47m Ω at V_{GS} = 10V, I_D = 4.5A
- Max $r_{DS(on)}$ = 53m Ω at V_{GS} = 6V, I_D = 4.5A
- Low Miller Charge
- Optimized efficiency at high frequencies
- UIS Capability (Single pulse and Repetitive pulse)
- RoHS Compliant

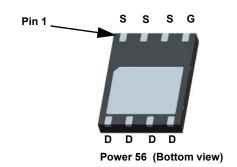


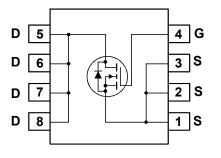
General Description

UltraFET devices combine characteristics that enable benchmark efficiency in power conversion applications. Optimized for $r_{DS(on)}$, low ESR, low total and Miller gate charge, these devices are ideal for high frequency DC to DC converters.

Application

- Distributed Power Architectures and VRMs
- Primary Switch for 24V and 48V Systems
- High Voltage Synchronous Rectifier





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			150	V
V _{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous (Package limited)	T _C = 25°C		27	
	-Continuous (Silicon limited)	T _C = 25°C		27	А
Ъ	-Continuous	T _A = 25°C	(Note 1a)	4.5	
	-Pulsed			30	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	150	mJ
P _D	Power Dissipation	T _C = 25°C		78	14/
	Power Dissipation $T_A = 25^{\circ}C$ (Note 1a)		(Note 1a)	2.5	W
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +150	°C

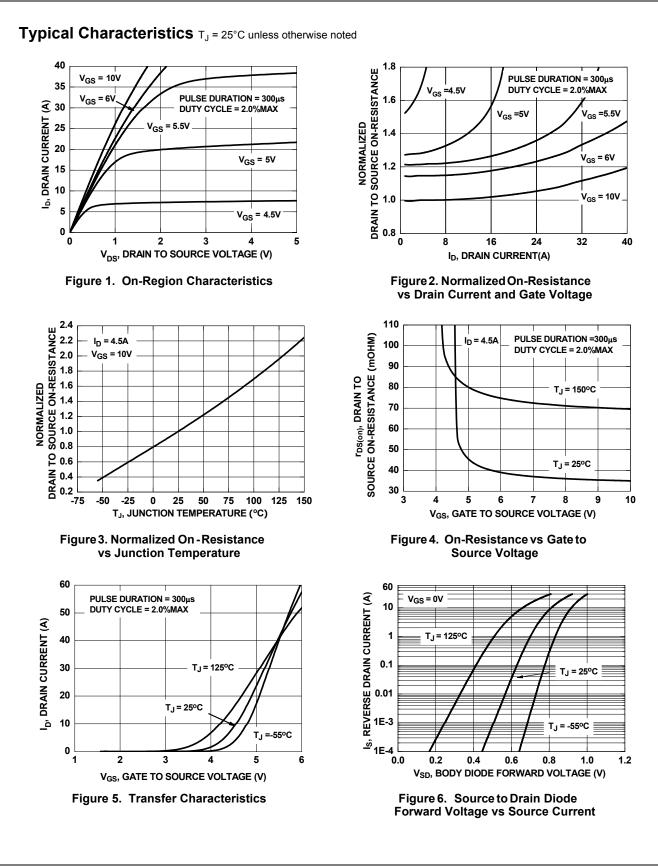
Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.6	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 50	0/00

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS2572	FDMS2572	Power 56	13"	12mm	3000 units

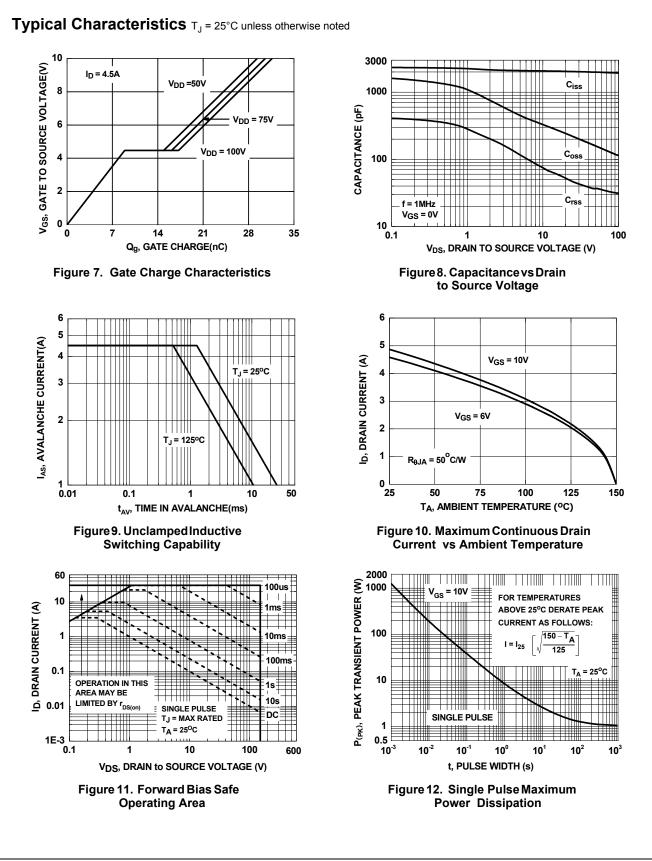
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	150			V
ΔBV_{DSS} $\Delta T_{.1}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to 25°C		180		mV/°C
	Zero Gate Voltage Drain Current	V _{DS} = 120V, V _{GS} = 0V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
	cteristics (Note 2)				1	1
	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	2	3	4	V
$V_{GS(th)} = \Delta V_{GS(th)}$	Gate to Source Threshold Voltage		2	5	4	v
$\frac{\Delta V GS(th)}{\Delta T_J}$	Temperature Coefficient	I_D = 250µA, referenced to 25°C		-9.8		mV/°C
		V _{GS} = 10V, I _D = 4.5A		36	47	-
DS(on)	Drain to Source On Resistance	$V_{GS} = 6V, I_{D} = 4.5A$		39	53	mΩ
		V_{GS} = 10V, I_D = 4.5A, T_J = 125°C		69	103	
9fs	Forward Transconductance	$V_{DS} = 10V, I_D = 4.5A$		14		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			1960	2610	pF
C _{oss}	Output Capacitance	─V _{DS} = 75V, V _{GS} = 0V, f = 1MHz		130	175	pF
C _{rss}	Reverse Transfer Capacitance			30	45	pF
R _g	Gate Resistance	f = 1MHz	0.1	1.3	2.6	Ω
t _{d(on)}	Turn-On Delay Time	V _{DD} = 75V, I _D = 1.0A		11 8	20 16	ns ns
t _{d(off)}	Turn-Off Delay Time	—V _{GS} = 10V, R _{GEN} = 6Ω		38	61	ns
t _f	Fall Time	-		31	50	ns
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V \text{ to } 10V$ $V_{DD} = 75V$		31	43	nC
<u>∽g(101)</u> Q _{gs}	Gate to Source Gate Charge	$I_{D} = 4.5A$		9		nC
Q _{gd}	Gate to Drain "Miller" Charge			7		nC
*	urce Diode Characteristics					
	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = 2.2A (Note 2)		0.7	1.0	V
V _{SD}	Reverse Recovery Time			67	1.0	ns
ur Q _{rr}	Reverse Recovery Charge	— I _F = 4.5A, di/dt = 100A/μs		130	195	nC
otes:	nined with the device mounted on a 1in ² pad 2 oz copper pa			by design wi	nile R _{θCA} is d	
	a.50°C/W when mount a 1 in ² pad of 2 oz copp	eu Uli min		en mounted of 2 oz coppe		
	€ <u></u>	T 88888				
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FDMS2572 Rev.C4

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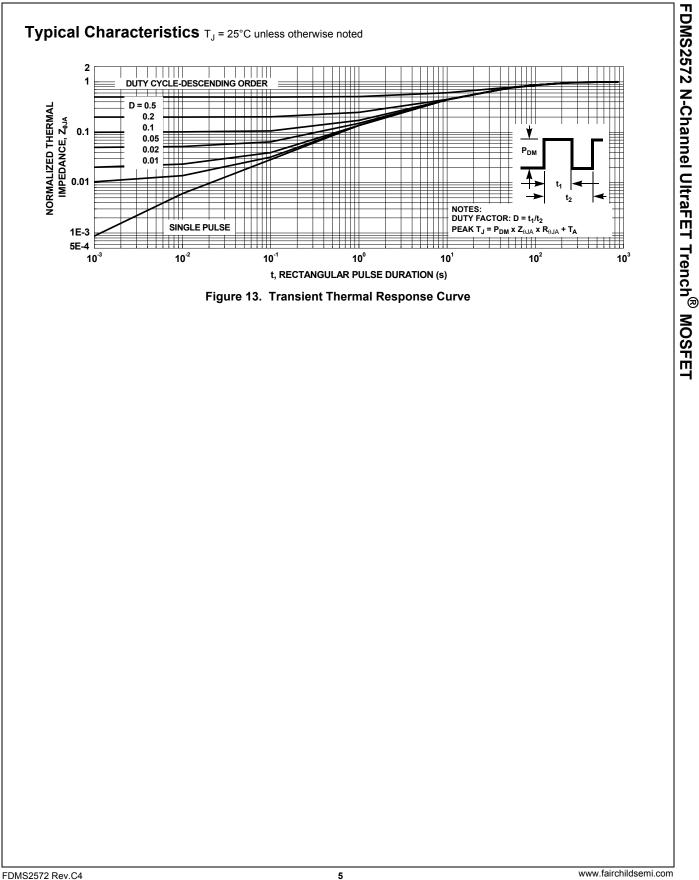
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2X 5.0 A -0.77 F 8 4.52 6.61 6.0 4.32 3.91-1 27 0.10 C 4 2X PIN #1 IDENT TOP VIEW 0.61 TYP 1.27 TYP RECOMMENDED LAND PATTERN -0.8 MAX // 0.10 C (0.25)____0.08 C ¢ 0.05 SIDE VIEW SEATING PLANE 3.86 🔕 0.64 0.44® 3.66 PIN #1 IDENT (OPTIONAL) 3.42 3.22 4.01? .10 i i 5 0.36-0.46 🚯 1.27 ⊕ 0.10 M C A B 3.81 ⊕ 0.05 M C 0 BOTTOM VIEW NOTES: ODES NOT FULLY CONFORM TO JEDEC REGISTRATION, MO-229. DATED 11/2001. B. DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994 D. TERMINALS 5,6,7 AND 8 ARE TIED TO THE EXPOSED PADDLE MLP08GrevD

FDMS2572 N-Channel UltraFET Trench[®] MOSFET

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